# THE DATASHEET OF

# MPS2907ARLG

# MPS2907A Series

# General Purpose Transistors

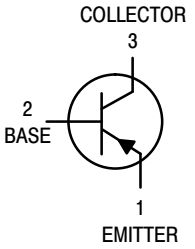
## PNP Silicon

ON Semiconductor®

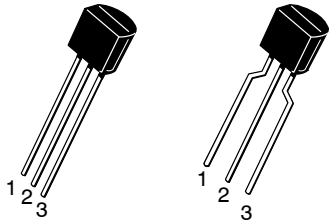
http://onsemi.com

### Features

- These are Pb−Free Devices*




**TO−92**
**CASE 29**
**STYLE 1**




STRAIGHT LEAD
BULK PACK

BENT LEAD
TAPE & REEL
AMMO PACK

### MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|---|---|---|
| Collector − Emitter Voltage | $V_{CEO}$ | −60 | Vdc |
| Collector − Base Voltage | $V_{CBO}$ | −60 | Vdc |
| Emitter − Base Voltage | $V_{EBO}$ | −5.0 | Vdc |
| Collector Current − Continuous | $I_C$ | −600 | mAdc |
| Total Device Dissipation @ $T_A$ = 25°C<br>Derate above 25°C | $P_D$ | 625<br>5.0 | mW<br>mW/°C |
| Total Device Dissipation @ $T_C$ = 25°C<br>Derate above 25°C | $P_D$ | 1.5<br>12 | W<br>mW/°C |
| Operating and Storage Junction Temperature Range | $T_J$, $T_{stg}$ | −55 to +150 | °C |

### THERMAL CHARACTERISTICS

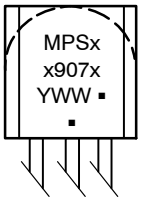
| Characteristic | Symbol | Max | Unit |
|---|---|---|---|
| Thermal Resistance, Junction−to−Ambient | $R_{\theta JA}$ | 200 | °C/W |
| Thermal Resistance, Junction−to−Case | $R_{\theta JC}$ | 83.3 | °C/W |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### DEVICE MARKING

| Device | Line 1 | Line 2 |
|---|---|---|
| MPS2907AG | MPS | 2907A |
| MPS2907ARLG | MPS2 | 907A |
| MPS2907ARLRAG | MPS | 2907 |
| MPS2907ARLRPG | MPS | 2907 |

### MARKING DIAGRAM




Y = Year
WW = Work Week
▪ = Pb−Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**ELECTRICAL CHARACTERISTICS** ($T_A$ = 25°C unless otherwise noted)

| Characteristic | | Symbol | Min | Max | Unit |
|---|---|---|---|---|---|
| **OFF CHARACTERISTICS** | | | | | |
| Collector – Emitter Breakdown Voltage (Note 1) ($I_C$ = −10 mAdc, $I_B$ = 0) | | $V_{(BR)CEO}$ | −60 | – | Vdc |
| Collector – Base Breakdown Voltage ($I_C$ = −10 μAdc, $I_E$ = 0) | | $V_{(BR)CBO}$ | −60 | – | Vdc |
| Emitter – Base Breakdown Voltage ($I_E$ = −10 μAdc, $I_C$ = 0) | | $V_{(BR)EBO}$ | −5.0 | – | Vdc |
| Collector Cutoff Current ($V_{CE}$ = −30 Vdc, $V_{EB(off)}$ = −0.5 Vdc) | | $I_{CEX}$ | – | −50 | nAdc |
| Collector Cutoff Current<br>($V_{CB}$ = −50 Vdc, $I_E$ = 0)<br>($V_{CB}$ = −50 Vdc, $I_E$ = 0, $T_A$ = 150°C) | | $I_{CBO}$ | <br>–<br>– | <br>−0.01<br>−10 | μAdc |
| Base Current ($V_{CE}$ = −30 Vdc, $V_{EB(off)}$ = −0.5 Vdc) | | $I_B$ | – | −50 | nAdc |
| **ON CHARACTERISTICS** | | | | | |
| DC Current Gain<br>($I_C$ = −0.1 mAdc, $V_{CE}$ = −10 Vdc)<br>($I_C$ = −1.0 mAdc, $V_{CE}$ = −10 Vdc)<br>($I_C$ = −10 mAdc, $V_{CE}$ = −10 Vdc)<br>($I_C$ = −150 mAdc, $V_{CE}$ = −10 Vdc) (Note 1)<br>($I_C$ = −500 mAdc, $V_{CE}$ = −10 Vdc) (Note 1) | | $h_{FE}$ | <br>75<br>100<br>100<br>100<br>50 | <br>–<br>–<br>–<br>300<br>– | – |
| Collector – Emitter Saturation Voltage (Note 1)<br>($I_C$ = −150 mAdc, $I_B$ = −15 mAdc)<br>($I_C$ = −500 mAdc, $I_B$ = −50 mAdc) | | $V_{CE(sat)}$ | <br>–<br>– | <br>−0.4<br>−1.6 | Vdc |
| Base – Emitter Saturation Voltage (Note 1)<br>($I_C$ = −150 mAdc, $I_B$ = −15 mAdc)<br>($I_C$ = −500 mAdc, $I_B$ = −50 mAdc) | | $V_{BE(sat)}$ | <br>–<br>– | <br>−1.3<br>−2.6 | Vdc |
| **SMALL−SIGNAL CHARACTERISTICS** | | | | | |
| Current – Gain – Bandwidth Product (Notes 1 and 2),<br>($I_C$ = −50 mAdc, $V_{CE}$ = −20 Vdc, f = 100 MHz) | | $f_T$ | 200 | – | MHz |
| Output Capacitance ($V_{CB}$ = −10 Vdc, $I_E$ = 0, f = 1.0 MHz) | | $C_{obo}$ | – | 8.0 | pF |
| Input Capacitance ($V_{EB}$ = −2.0 Vdc, $I_C$ = 0, f = 1.0 MHz) | | $C_{ibo}$ | – | 30 | pF |
| **SWITCHING CHARACTERISTICS** | | | | | |
| Turn−On Time | ($V_{CC}$ = −30 Vdc, $I_C$ = −150 mAdc, $I_{B1}$ = −15 mAdc) (Figures 1 and 5) | $t_{on}$ | – | 45 | ns |
| Delay Time | | $t_d$ | – | 10 | ns |
| Rise Time | | $t_r$ | – | 40 | ns |
| Turn−Off Time | ($V_{CC}$ = −6.0 Vdc, $I_C$ = −150 mAdc, $I_{B1}$ = $I_{B2}$ = 15 mAdc) (Figure 2) | $t_{off}$ | – | 100 | ns |
| Storage Time | | $t_s$ | – | 80 | ns |
| Fall Time | | $t_f$ | – | 30 | ns |

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
2. $f_T$ is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

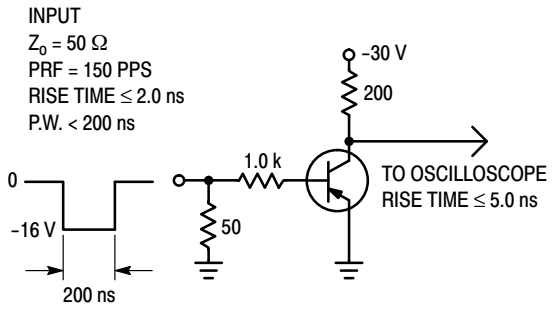



**Figure 1. Delay and Rise Time Test Circuit**

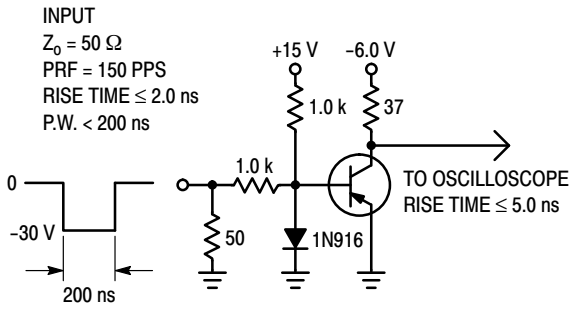



**Figure 2. Storage and Fall Time Test Circuit**

## TYPICAL CHARACTERISTICS

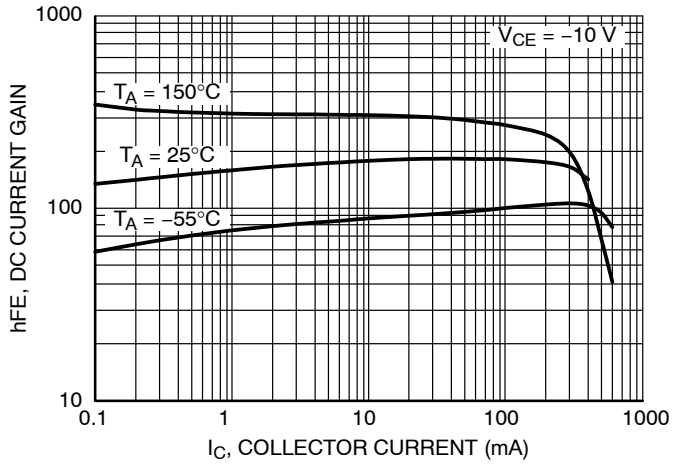



**Figure 3. DC Current Gain**

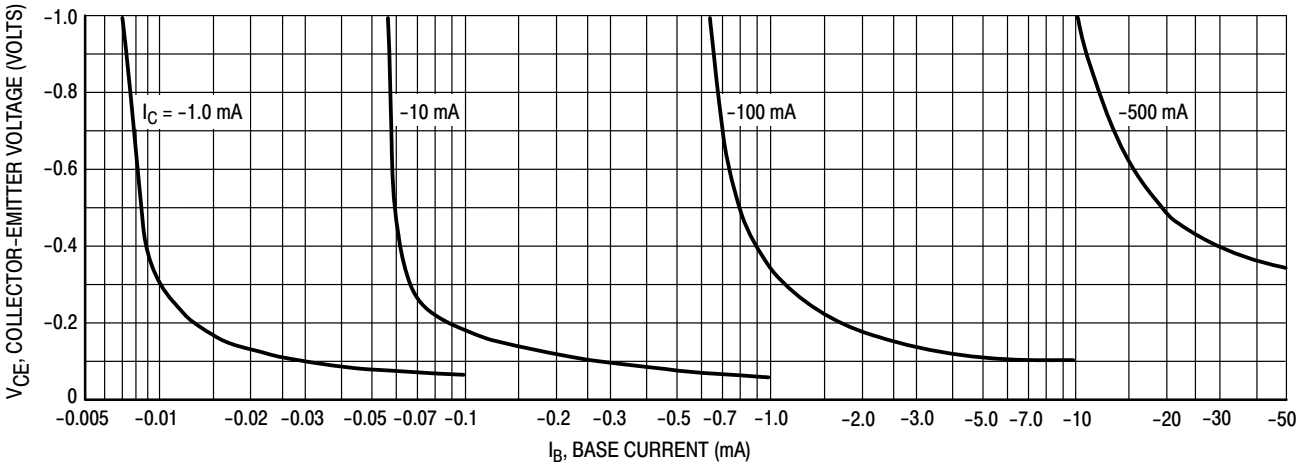



**Figure 4. Collector Saturation Region**

**ORDERING INFORMATION**

| Device | Package | Shipping† |
|---|---|---|
| MPS2907AG | TO−92<br>(Pb−Free) | 5000 Units / Bulk |
| MPS2907ARLG | TO−92<br>(Pb−Free) | 2000 / Tape & Reel |
| MPS2907ARLRAG | TO−92<br>(Pb−Free) | |
| MPS2907ARLRPG | TO−92<br>(Pb−Free) | 2000 / Ammo Pack |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

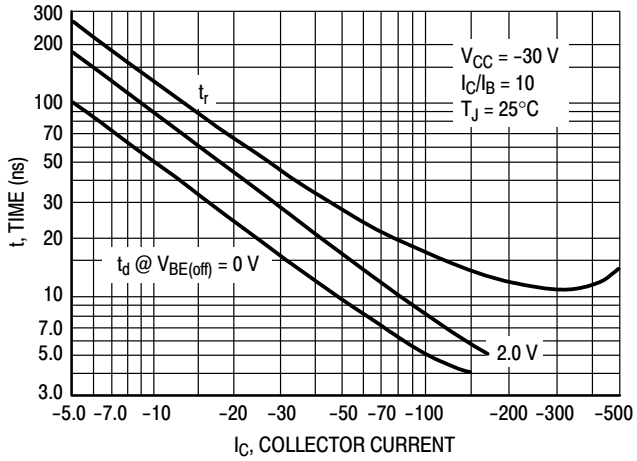



**Figure 5. Turn−On Time**

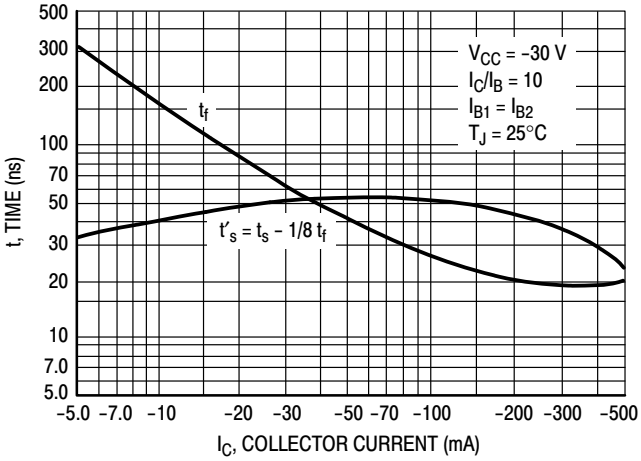



**Figure 6. Turn−Off Time**

## TYPICAL SMALL−SIGNAL CHARACTERISTICS

### NOISE FIGURE

$V_{CE}$ = 10 Vdc, $T_A$ = 25°C

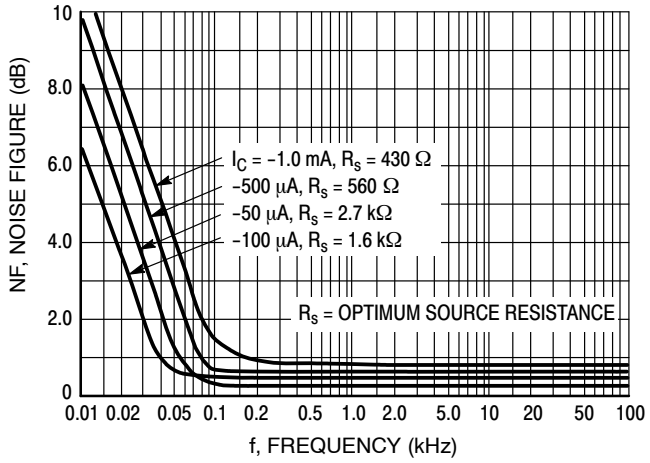



**Figure 7. Frequency Effects**

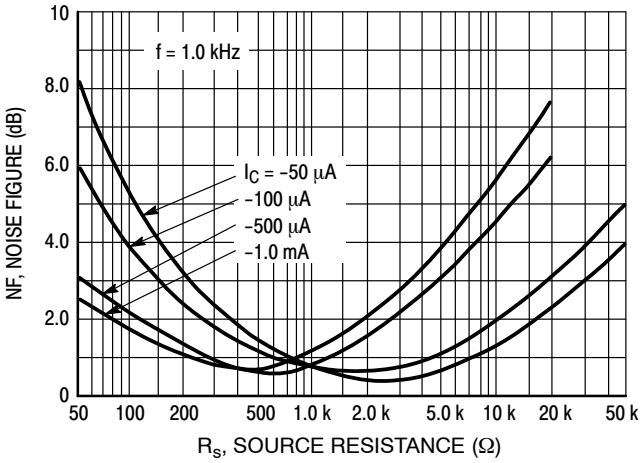



**Figure 8. Source Resistance Effects**

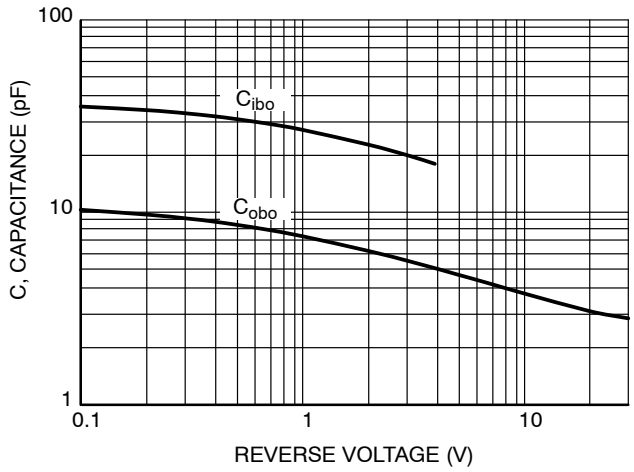



**Figure 9. Capacitances**

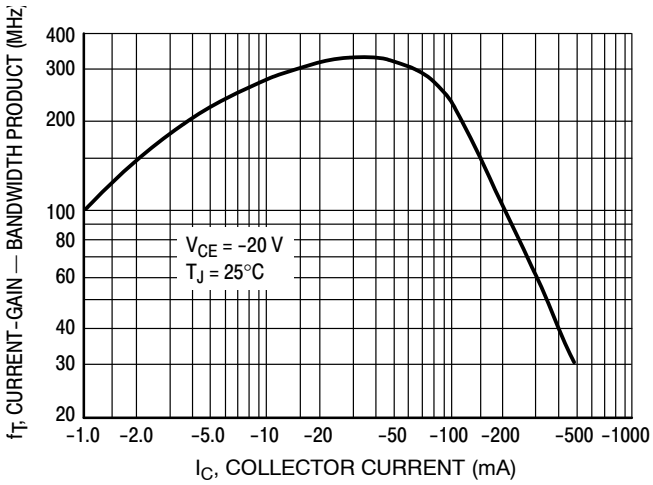



**Figure 10. Current−Gain − Bandwidth Product**

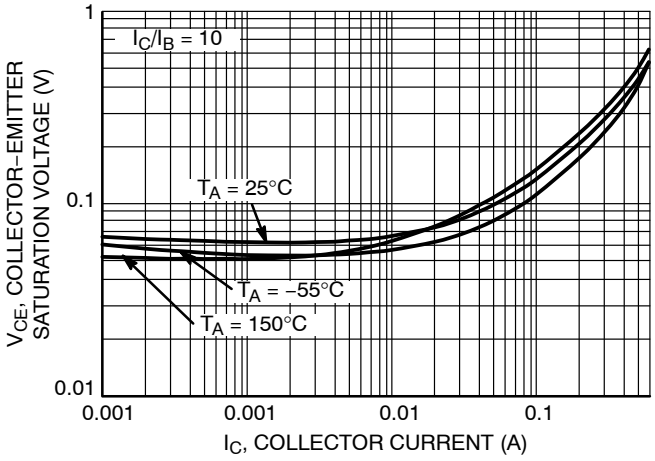



**Figure 11. Collector−Emitter Saturation Voltage vs. Collector Current**

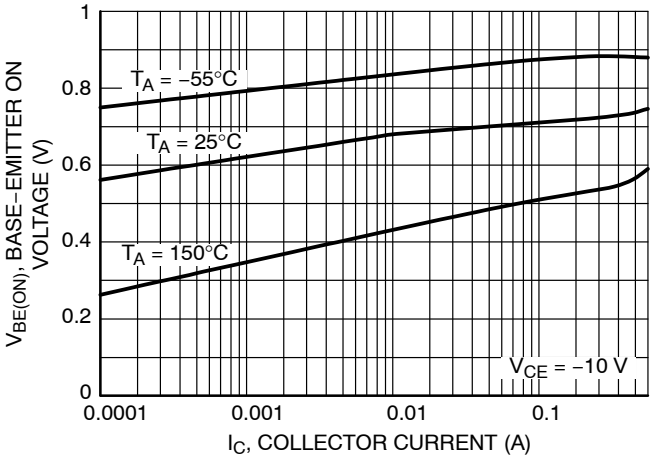



**Figure 12. Base−Emitter Turn−ON Voltage vs. Collector Current**

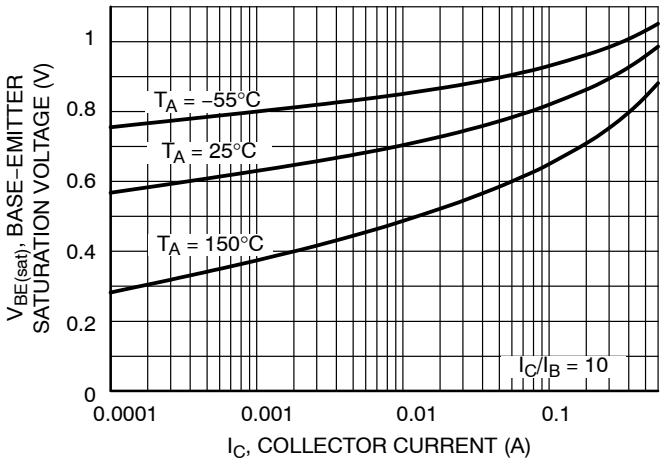



**Figure 13. Base Emitter Saturation Voltage vs. Collector Current**

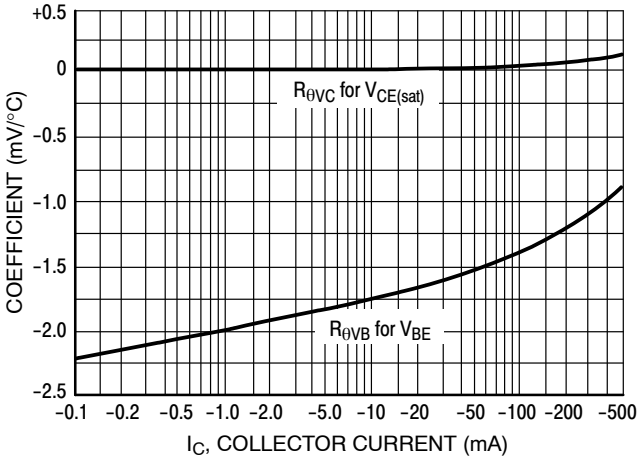


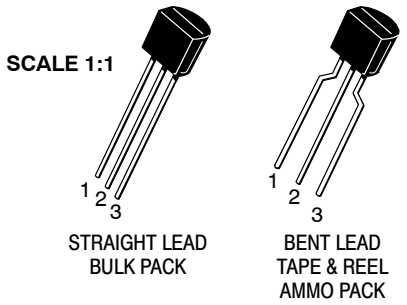

**Figure 14. Temperature Coefficients**

# MECHANICAL CASE OUTLINE
## PACKAGE DIMENSIONS

ON Semiconductor®

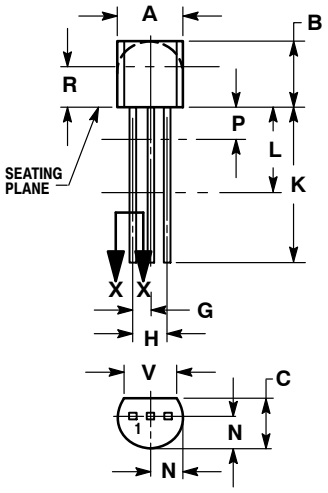
**TO–92 (TO–226)**
CASE 29–11
ISSUE AM

DATE 09 MAR 2007

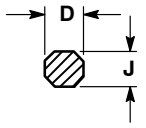



STRAIGHT LEAD
BULK PACK

BENT LEAD
TAPE & REEL
AMMO PACK



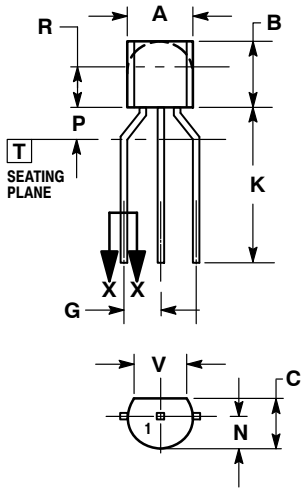

STRAIGHT LEAD
BULK PACK



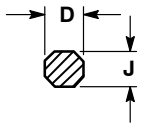

**SECTION X–X**

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INCHES | | MILLIMETERS | |
|---|---|---|---|---|
| DIM | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.45 | 5.20 |
| B | 0.170 | 0.210 | 4.32 | 5.33 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.021 | 0.407 | 0.533 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.250 | --- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.115 | --- | 2.93 | --- |
| V | 0.135 | --- | 3.43 | --- |




BENT LEAD
TAPE & REEL
AMMO PACK




**SECTION X–X**

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | MILLIMETERS | |
|---|---|---|
| DIM | MIN | MAX |
| A | 4.45 | 5.20 |
| B | 4.32 | 5.33 |
| C | 3.18 | 4.19 |
| D | 0.40 | 0.54 |
| G | 2.40 | 2.80 |
| J | 0.39 | 0.50 |
| K | 12.70 | --- |
| N | 2.04 | 2.66 |
| P | 1.50 | 4.00 |
| R | 2.93 | --- |
| V | 3.43 | --- |

**STYLES ON PAGE 2**

| | | |
|---|---|---|
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| **STATUS:** | **ON SEMICONDUCTOR STANDARD** | |
| **NEW STANDARD:** | | |
| **DESCRIPTION:** | **TO–92 (TO–226)** | **PAGE 1 OF 3** |

**TO−92 (TO−226)**
CASE 29−11
ISSUE AM

DATE 09 MAR 2007

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 2:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 5:
PIN 1. DRAIN
2. SOURCE
3. GATE

STYLE 6:
PIN 1. GATE
2. SOURCE & SUBSTRATE
3. DRAIN

STYLE 7:
PIN 1. SOURCE
2. DRAIN
3. GATE

STYLE 8:
PIN 1. DRAIN
2. GATE
3. SOURCE & SUBSTRATE

STYLE 9:
PIN 1. BASE 1
2. EMITTER
3. BASE 2

STYLE 10:
PIN 1. CATHODE
2. GATE
3. ANODE

STYLE 11:
PIN 1. ANODE
2. CATHODE & ANODE
3. CATHODE

STYLE 12:
PIN 1. MAIN TERMINAL 1
2. GATE
3. MAIN TERMINAL 2

STYLE 13:
PIN 1. ANODE 1
2. GATE
3. CATHODE 2

STYLE 14:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

STYLE 15:
PIN 1. ANODE 1
2. CATHODE
3. ANODE 2

STYLE 16:
PIN 1. ANODE
2. GATE
3. CATHODE

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

STYLE 18:
PIN 1. ANODE
2. CATHODE
3. NOT CONNECTED

STYLE 19:
PIN 1. GATE
2. ANODE
3. CATHODE

STYLE 20:
PIN 1. NOT CONNECTED
2. CATHODE
3. ANODE

STYLE 21:
PIN 1. COLLECTOR
2. EMITTER
3. BASE

STYLE 22:
PIN 1. SOURCE
2. GATE
3. DRAIN

STYLE 23:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 24:
PIN 1. EMITTER
2. COLLECTOR/ANODE
3. CATHODE

STYLE 25:
PIN 1. MT 1
2. GATE
3. MT 2

STYLE 26:
PIN 1. $V_{CC}$
2. GROUND 2
3. OUTPUT

STYLE 27:
PIN 1. MT
2. SUBSTRATE
3. MT

STYLE 28:
PIN 1. CATHODE
2. ANODE
3. GATE

STYLE 29:
PIN 1. NOT CONNECTED
2. ANODE
3. CATHODE

STYLE 30:
PIN 1. DRAIN
2. GATE
3. SOURCE

STYLE 31:
PIN 1. GATE
2. DRAIN
3. SOURCE

STYLE 32:
PIN 1. BASE
2. COLLECTOR
3. EMITTER

STYLE 33:
PIN 1. RETURN
2. INPUT
3. OUTPUT

STYLE 34:
PIN 1. INPUT
2. GROUND
3. LOGIC

STYLE 35:
PIN 1. GATE
2. COLLECTOR
3. EMITTER

| ISSUE | REVISION | DATE |
|---|---|---|
| AM | ADDED BENT−LEAD TAPE & REEL VERSION. REQ. BY J. SUPINA. | 09 MAR 2007 |
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## ADDITIONAL INFORMATION

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- Excess Inventory Management